NSN 5962-01-124-9565 Memory Microcircuit - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5962-01-124-9565		
Body Length:		
0.840 inches		
Body Width:		
0.310 inches		
Body Height:		
0.185 inches		
Maximum Power Dissipation Rating:		
794.0 milliwatts		
Operating Tempurature Range:		
-55.0/+125.0 degrees celsius		
Storage Tempurature Range:		
-65.0/+150.0 degrees celsius		
Features Provided:		
Monolithic and bipolar and schottky		
Inclosure Material:		
Ceramic		
Inclosure Configuration:		
Dual-in-line		
Output Logic Form:		
Transistor-transistor logic		
Input Circuit Pattern:		
10 input		
Terminal Surface Treatment:		
Solder		
Voltage Rating And Type Per Characteristic:		
-0.5 volts power source and 7.0 volts power source		
Time Rating Per Chacteristic:		
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time	ne, high to low l	evel
output		
Memory Device Type:		
Prom		
Terminal Type And Quantity:		
16 printed circuit		
Shelf Life:		
N/a		
Unit Of Measure:		
 Demilitarization:		
Yes - demil/mli		
Fiig:		
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